

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE30H11BK uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =30V,I_D =110A

 $R_{DS(ON)}$ =3.2m Ω (typical) @ V_{GS} =10V

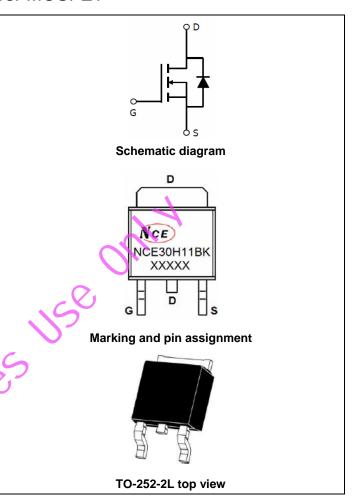
 $R_{DS(ON)}$ =4.0m Ω (typical) @ V_{GS} =4.5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- DC/DC converters
- Synchronous Rectifier

100% UIS TESTED!



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE30H11BK	NCE30H11BK	TO-252-2L	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	110	А
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	77.8	А
Pulsed Drain Current	I _{DM}	330	Α
Maximum Power Dissipation	В	115	W
Derating factor	P _D	0.77	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	300	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ heta JC}$	1.36	°C/W



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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics				•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	30	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	V _{DS} =30V,V _{GS} =0V -		1	μΑ	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V		-	±100	nA	
On Characteristics (Note 3)	•		•	•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1	1.5	2.2	V	
Drain Course On Chata Basistanas		V _{GS} =10V, I _D =20A	-	3.2	3.9	0	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =20A		4.0	5.0	mΩ	
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A	20	-	-	S	
Dynamic Characteristics (Note4)		•	14	Į.		•	
Input Capacitance	C _{lss})/ 45\/\/ 0\	-	3009	-	PF	
Output Capacitance	Coss	V _{DS} =15V,V _{GS} =0V,	-	451	-	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	403	-	PF	
Switching Characteristics (Note 4)	•	160	•	•			
Turn-on Delay Time	t _{d(on)}		-	11	-	nS	
Turn-on Rise Time	t _r	V _{DD} =15V,I _D =20A	-	14	-	nS	
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V,R _{GEN} =3 Ω	-	36	-	nS	
Turn-Off Fall Time	t _f		-	12	-	nS	
Total Gate Charge	Q_g	V -45V/L -20A	-	66.3	-	nC	
Gate-Source Charge	Qgs	$V_{DS}=15V,I_{D}=20A,$	-	7.0	-	nC	
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	17.2	-	nC	
Drain-Source Diode Characteristics				•			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	110	Α	
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 20A	-	29	-	nS	
Reverse Recovery Charge	Qrr	di/dt = 100A/μs ^(Note3)	-	32	-	nC	
	•						

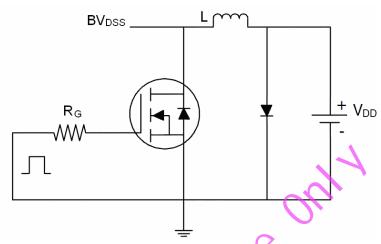
Notes:

- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature.}$
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- $\textbf{5.} \ \text{EAS condition:} \ \ Tj\text{=}25\,^{\circ}\text{C}, \ V_{DD}\text{=}15\text{V}, V_{G}\text{=}10\text{V}, L\text{=}0.5\text{mH}, \ Rg\text{=}25\Omega; \\$

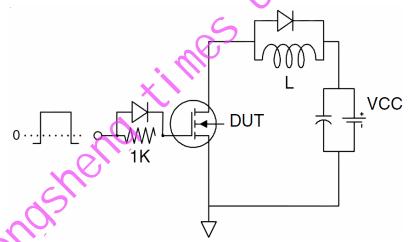


Test Circuit

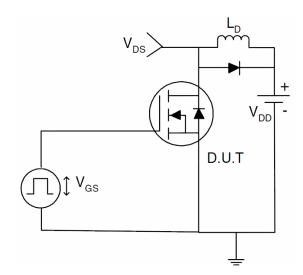
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

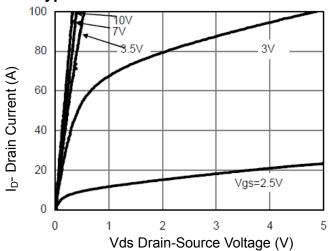


Figure 1 Output Characteristics

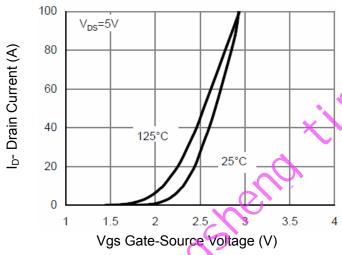


Figure 2 Transfer Characteristics

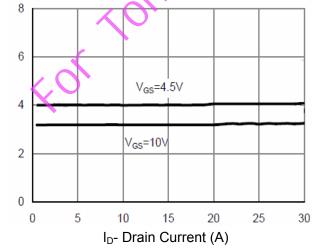


Figure 3 Rdson- Drain Current

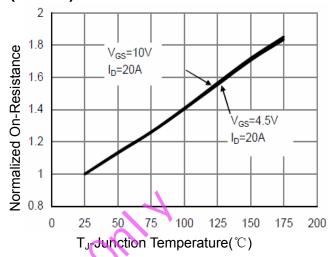
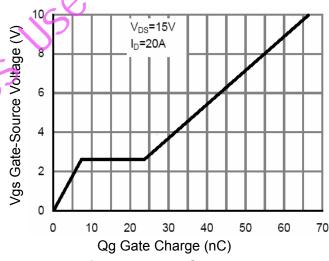


Figure 4 Rdson-Junction Temperature



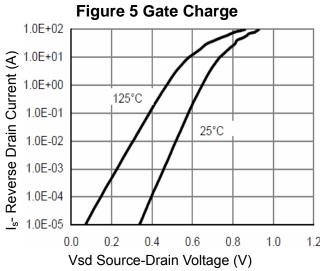


Figure 6 Source- Drain Diode Forward



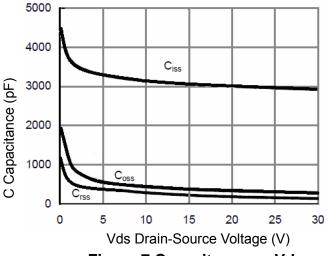


Figure 7 Capacitance vs Vds

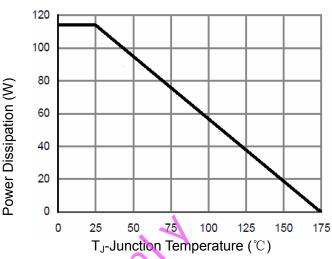


Figure 9 Power De-rating

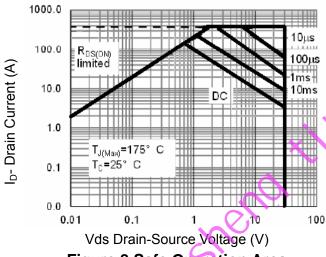


Figure 8 Safe Operation Area

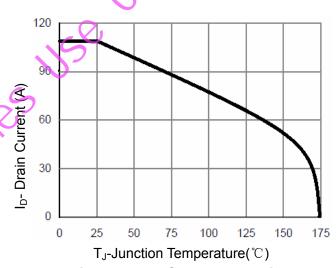
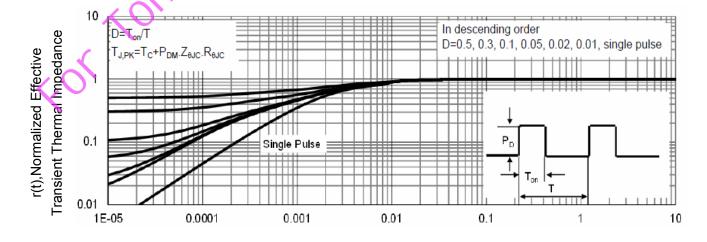


Figure 10 ID Current Derating

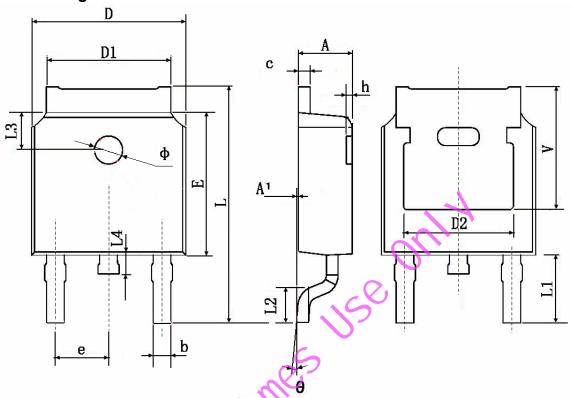


Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252-2L Package Information



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2 /	0.483	TYP.	0.190 TYP.		
E	6.000	6.200	0.236	0.244	
e 🇸	2.186	2.386	0.086	0.094	
10,	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		

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NCE30H11BK

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